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SN74AHC1G86

SCLS323N - MARCH 1996-REVISED DECEMBER 2014

# SN74AHC1G86 Single 2-Input Exclusive-OR Gate

#### 1 Features

- Operating Range of 2 V to 5.5 V
- Max t<sub>pd</sub> of 8 ns at 5 V
- Low Power Consumption, 10-µA Max I<sub>CC</sub>
- ±8-mA Output Drive at 5 V
- Schmitt-Trigger Action at All Inputs Makes the Circuit Tolerant for Slower Input Rise and Fall Time
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model
  - 200-V Machine Model
  - 1000-V Charged-Device Model

### 2 Applications

- Cameras
- Programmable Logic Controllers
- **Telecom Infrastructure** •
- Wireless Headsets
- Motor Drives and Controls
- TVs
- Set-top-boxes
- Audio •

## 3 Description

The SN74AHC1G86 is a single 2-input exclusive-OR gate. The device performs the Boolean function Y = A $\times$  B or Y =  $\overline{AB}$  +  $\overline{AB}$  in positive logic.

#### Device Information<sup>(1)</sup>

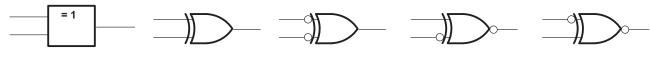
PART NUMBER	PACKAGE	BODY SIZE (NOM)						
	SOT-23 (5)	2.90 mm x 1.60 mm						
SN74AHC1G86	SC-70 (5)	2.00 mm x 1.30 mm						
	SOT-553 (5)	1.65 mm x 1.20 mm						

(1) For all available packages, see the orderable addendum at the end of the data sheet.

# 4 Simplified Schematic

An exclusive-OR gate has many applications, some of which can be represented better by alternative logic symbols.

EXCLUSIVE OR



These are five equivalent exclusive-OR symbols valid for an SN74AHC1G86 gate in positive logic; negation may be shown at any twoports.

## LOGIC-IDENTITY ELEMENT



The output is active (low) if all inputs stand at the same logic level (that is, A = B).

#### **EVEN-PARITY ELEMENT**



The output is active (low) if an even number of inputs (that is, 0 or 2) are active.

**ODD-PARITY ELEMENT** 



The output is active (high) if an odd number of inputs (that is, only 1 of the 2) are active.



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# 5 Revision History

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CI	hanges from Revision M (June 2005) to Revision N	Page
•	Added Applications, Device Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Typical Characteristics, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.	
•	Deleted Ordering Information table.	1
•	Changed MAX operating temperature to 125°C in Recommended Operating Conditions table.	4

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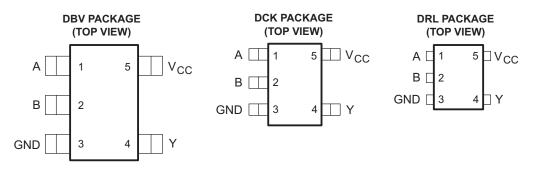
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#### 2



# 6 Pin Configuration and Functions



See mechanical drawings for dimensions.

Pin Functions									
	PIN	TYPE	DESCRIPTION						
NO.	NAME	ITPE	DESCRIPTION						
1	А	I	Input A						
2	В	I	Input B						
3	GND	_	Ground Pin						
4	Y	0	Output Y						
5	V <sub>CC</sub>	—	Power Pin						

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### 7 Specifications

### 7.1 Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
$V_{CC}$	Supply voltage range	range $^{(2)}$ ge range $^{(2)}$ currentvurrentvurrentV_0 < 0 or V_0 > V_{CC}utput currentV_0 = 0 to V_{CC}				
VI	Input voltage range <sup>(2)</sup>					
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA	
I <sub>OK</sub>	Output clamp current	$V_{O}$ < 0 or $V_{O}$ > $V_{CC}$		±20	mA	
I <sub>O</sub>	Continuous output current	$V_{O} = 0$ to $V_{CC}$		±25	mA	
	Continuous channel current through $V_{CC}$ or GND	nannel current through V <sub>CC</sub> or GND				
T <sub>stg</sub>	Storage temperature range		-65	150	°C	

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 7.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all $\ensuremath{pins^{(2)}}$	1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		2	5.5	V
		$V_{CC} = 2 V$	1.5		
V <sub>IH</sub>	High-level input voltage	$V_{CC} = 3 V$	2.1		V
		$V_{CC} = 5.5 V$	3.85		
		$V_{CC} = 2 V$		0.5	
	Low-level input voltage $V_{CC} = 3 V$	$V_{CC} = 3 V$		0.9	V
		V <sub>CC</sub> = 5.5 V		1.65	
VI	Input voltage		0	5.5	V
Vo	Output voltage		0	$V_{CC}$	V
		$V_{CC} = 2 V$		-50	μA
I <sub>OH</sub>	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	~ ^
		$V_{CC} = 5 V \pm 0.5 V$		-8	mA
		$V_{CC} = 2 V$		50	μA
I <sub>OL</sub>	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	~ ^
		$V_{CC} = 5 V \pm 0.5 V$		8	mA
A#/A.	Input transition rise or fell rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100	201
$\Delta t / \Delta v$	Input transition rise or fall rate	$V_{CC} = 5 V \pm 0.5 V$		20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

 All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).

### 7.4 Thermal Information

			SN74AHC1G86					
	THERMAL METRIC <sup>(1)</sup>	DBV	DBV DCK DRL					
			5 PINS					
$R_{\theta JA}$	Junction-to-ambient thermal resistance	231.3	287.6	328.7				
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	119.9	97.7	105.1				
$R_{\theta JB}$	Junction-to-board thermal resistance	60.6	65.	150.3	°C/W			
ΨJT	Junction-to-top characterization parameter	17.8	2.0	6.9				
$\Psi_{JB}$	Junction-to-board characterization parameter	60.1	64.2	148.4				

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

## 7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T	∠ = 25°C		–40°C to	85°C	-40°C to 125°C		UNIT
PARAMETER	TER TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		2 V	1.9	2		1.9		1.9		
	I <sub>OH</sub> = -50 μA	3 V	2.9	3		2.9		2.9		
V <sub>OH</sub>		4.5 V	4.4	4.5		4.4		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		2.48		
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8		
		2 V			0.1		0.1		0.1	
	I <sub>OL</sub> = 50 μA	3 V			0.1		0.1		0.1	
V <sub>OL</sub>		4.5 V			0.1		0.1		0.1	V
	I <sub>OL</sub> = 4 mA	3 V			0.36		0.44		0.44	
	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44		0.44	
lı	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V			±0.1		±1		±1	μA
I <sub>CC</sub>	$V_I = V_{CC} \text{ or } GND, \qquad I_O = 0$	5.5 V			1		10		10	μA
Ci	$V_{I} = V_{CC}$ or GND	5 V		4	10		10		10	pF

## 7.6 Switching Characteristics, $V_{CC} = 3.3 V \pm 0.3 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

DADAMETED	FROM	то	LOAD	т	<sub>A</sub> = 25°C		–40°C t	o 85°C	–40°C to	125°C	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	A an D	V	0 45 -5		7	11	1	13	1	14	
t <sub>PHL</sub>	A or B	ř	C <sub>L</sub> = 15 pF		7	11	1	13	1	14	ns
t <sub>PLH</sub>	A or B	V	0 50 - 5		9.5	14.5	1	16.5	1	17.5	
t <sub>PHL</sub>		ř	C <sub>L</sub> = 50 pF		9.5	14.5	1	16.5	1	17.5	ns

## 7.7 Switching Characteristics, $V_{cc} = 5 V \pm 0.5 V$

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 3)

DADAMETED	FROM	то	LOAD	T	<sub>A</sub> = 25°C		–40°C te	o 85°C	–40°C to	125°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNIT
t <sub>PLH</sub>	A	V	0 45 -5		4.8	6.8	1	8	1	8.6	
t <sub>PHL</sub>	A or B	ř	C <sub>L</sub> = 15 pF		4.8	6.8	1	8	1	8.6	ns
t <sub>PLH</sub>	4 D	V	0 50 - 5		6.3	8.8	1	10	1	11	
t <sub>PHL</sub>	A or B	ř	C <sub>L</sub> = 50 pF		6.3	8.8	1	10	1	11	ns

#### SN74AHC1G86

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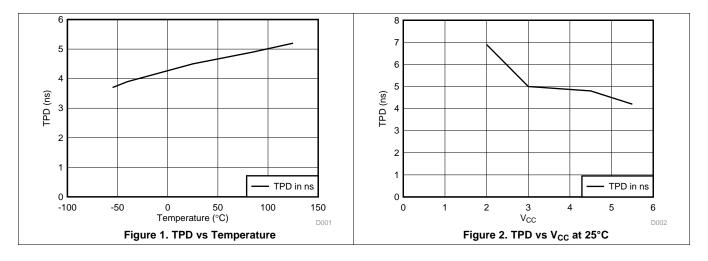
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# 7.8 Operating Characteristics

 $V_{CC}$  = 5 V,  $T_A$  = 25°C

	PARAMETER	TEST CO	ONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	18	pF

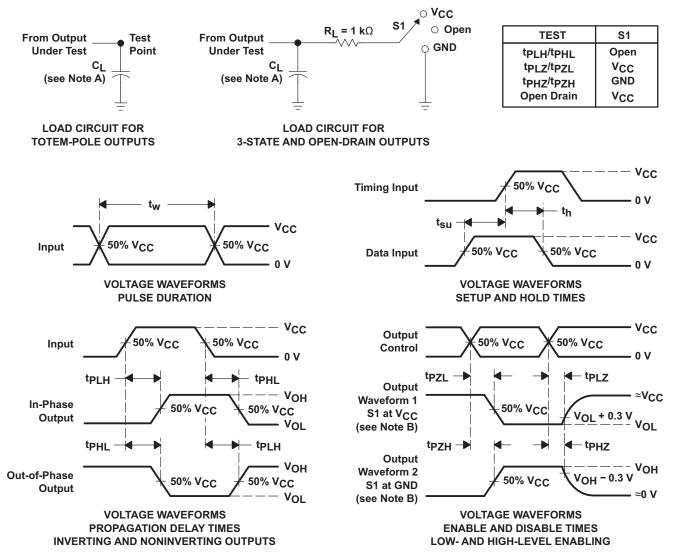
## 7.9 Typical Characteristics



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### 8 Parameter Measurement Information



NOTES: A. CL includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>Q</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  3 ns, t<sub>f</sub>  $\leq$  3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.

#### Figure 3. Load Circuit and Voltage Waveforms



### 9 Detailed Description

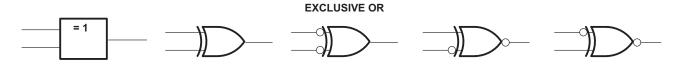
#### 9.1 Overview

The SN74AHC1G86 is a single 2-input exclusive-OR gate. The device performs the Boolean function  $Y = A \times B$  or  $Y = \overline{AB} + A\overline{B}$  in positive logic.

A common application is as a true or complementary element. If one of the inputs is low, the other input is reproduced in true form at the output. If one of the inputs is high, the signal on the other input is reproduced inverted at the output.

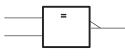
#### 9.2 Functional Block Diagram

An exclusive-OR gate has many applications, some of which can be represented better by alternative logic symbols.



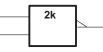
These are five equivalent exclusive-OR symbols valid for an SN74AHC1G86 gate in positive logic; negation may be shown at any two ports.

LOGIC-IDENTITY ELEMENT



The output is active (low) if all inputs stand at the same logic level (that is, A = B).

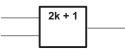
#### **EVEN-PARITY ELEMENT**



The output is active (low) if an even number of inputs (that is, 0 or 2) are active.

Figure 4. Exclusive-OR Logic

#### **ODD-PARITY ELEMENT**



The output is active (high) if an odd number of inputs (that is, only 1 of the 2) are active.

### 9.3 Feature Description

- Wide operating voltage range
  Operates from 2 V to 5.5 V
- Allows down-voltage translation
  - Inputs accept voltages to 5.5 V
- · The low drive and slow edge rates will minimize overshoot and undershoot on the outputs

### 9.4 Device Functional Modes

INP	UTS	OUTPUT Y					
Α	В						
L	L	L					
L	Н	Н					
н	L	Н					
н	н	L					

#### Table 1. Function Table



### **10** Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### **10.1** Application Information

SN74AHCT1G125 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs can accept voltages to 5.5 V at any valid  $V_{CC}$  making it Ideal for down translation.

### **10.2 Typical Application**

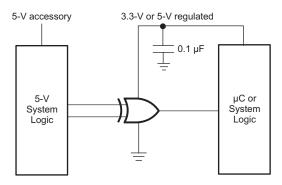


Figure 5. Typical Application Schematic

### 10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads, so routing and load conditions should be considered to prevent ringing.

### 10.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
  - For rise time and fall time specifications, see Δt/ΔV in the Recommended Operating Conditions table.
  - For specified High and low levels, see  $V_{IH}$  and  $V_{IL}$  in the *Recommended Operating Conditions* table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V<sub>CC</sub>.
- 2. Recommend Output Conditions
  - Load currents should not exceed 25 mA per output and 50 mA total for the part.
  - Outputs should not be pulled above V<sub>CC</sub>.



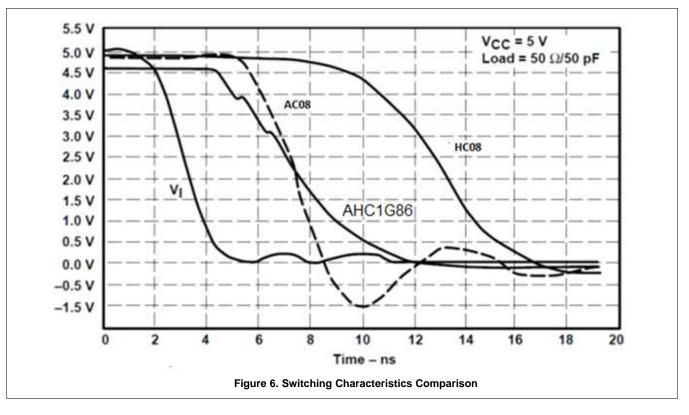
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### Typical Application (continued)

#### 10.2.3 Application Curves



## **11 Power Supply Recommendations**

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the *Recommended Operating Conditions* table.

Each V<sub>CC</sub> pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1  $\mu$ F is recommended. If there are multiple V<sub>CC</sub> pins, 0.01  $\mu$ F or 0.022  $\mu$ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1  $\mu$ F and 1  $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.



## 12 Layout

### 12.1 Layout Guidelines

When using multiple bit logic devices, inputs should not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in Figure 7 are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

### 12.2 Layout Example

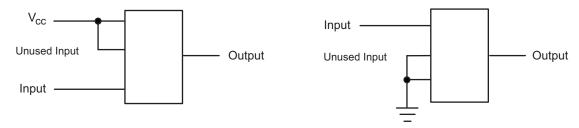


Figure 7. Layout Diagram

## **13** Device and Documentation Support

### 13.1 Trademarks

All trademarks are the property of their respective owners.

### 13.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 13.3 Glossary

#### SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

### 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
	. ,					.,	(6)	.,			
SN74AHC1G86DBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	(A863, A86G, A86J, A86S)	Samples
SN74AHC1G86DBVRE4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	A86G	Samples
SN74AHC1G86DBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	A86G	Samples
SN74AHC1G86DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	(AH3, AHG, AHJ, AH S)	Samples
SN74AHC1G86DCKRE4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AH3	Samples
SN74AHC1G86DCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AH3	Samples
SN74AHC1G86DCKTG4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AH3	Samples
SN74AHC1G86DRLR	ACTIVE	SOT-5X3	DRL	5	4000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	AHS	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:**The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN74AHC1G86 :

- Automotive : SN74AHC1G86-Q1
- Enhanced Product : SN74AHC1G86-EP

NOTE: Qualified Version Definitions:

- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications

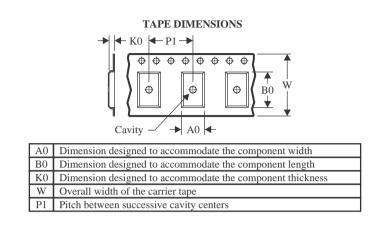


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### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC1G86DBVR	SOT-23	DBV	5	3000	178.0	9.2	3.3	3.23	1.55	4.0	8.0	Q3
SN74AHC1G86DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G86DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
SN74AHC1G86DBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
SN74AHC1G86DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHC1G86DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
SN74AHC1G86DCKRG4	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHC1G86DCKTG4	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AHC1G86DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3



# PACKAGE MATERIALS INFORMATION

13-Aug-2023



All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC1G86DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74AHC1G86DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AHC1G86DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74AHC1G86DBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
SN74AHC1G86DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AHC1G86DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AHC1G86DCKRG4	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AHC1G86DCKTG4	SC70	DCK	5	250	180.0	180.0	18.0
SN74AHC1G86DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0

# **DCK0005A**



# **PACKAGE OUTLINE**

# SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.



# **DCK0005A**

# **EXAMPLE BOARD LAYOUT**

# SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

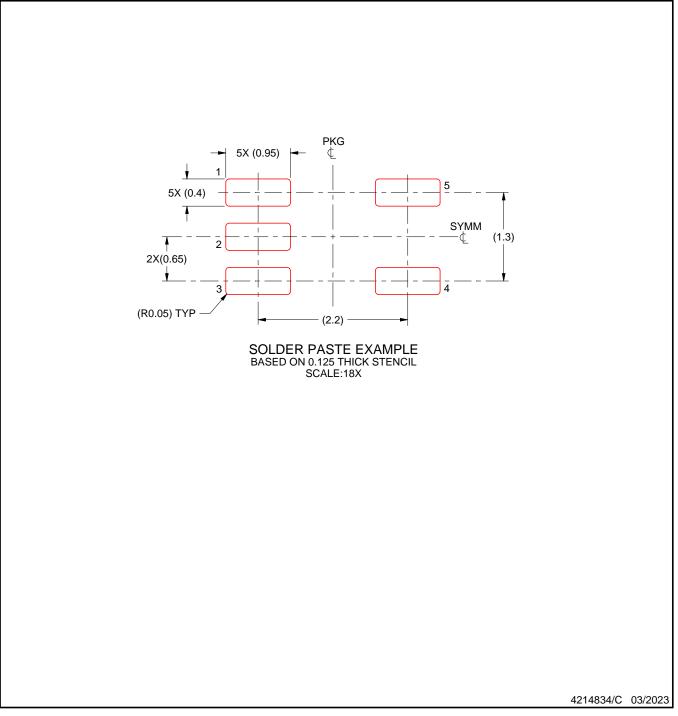


# DCK0005A

# **EXAMPLE STENCIL DESIGN**

# SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Board assembly site may have different recommendations for stencil design.



<sup>6.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

# **DBV0005A**



# **PACKAGE OUTLINE**

# SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



# DBV0005A

# **EXAMPLE BOARD LAYOUT**

# SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DBV0005A

# **EXAMPLE STENCIL DESIGN**

# SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



# **DRL0005A**



# **PACKAGE OUTLINE**

# SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-293 Variation UAAD-1



# **DRL0005A**

# **EXAMPLE BOARD LAYOUT**

# SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# **DRL0005A**

# **EXAMPLE STENCIL DESIGN**

# SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

8. Board assembly site may have different recommendations for stencil design.



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